MP7542



5 V CMOS 4-Bit Input, 12-Bit Digital-to-Analog Converter

FEATURES

- 12-Bit DAC with a 4-Bit Parallel Address for 4 & 8-Bit Microprocessor or Microcontroller Interface
- Nonlinearity +1/2 LSB Tmin to Tmax
- Latch-Up Free
- Low Sensitivity to Output Amplifier V_{OS}
- Low Output Capacitance

- +5 V Supply Operation
- Low Power Consumption: 40mW Max.
- Low Cost
- Serial Version: MP7543

GENERAL DESCRIPTION

The MP7542 is a precision, 12-bit CMOS 4-quadrant multiplying Digital-to-Analog Converter designed for direct interface to 4 and 8-bit microprocessors.

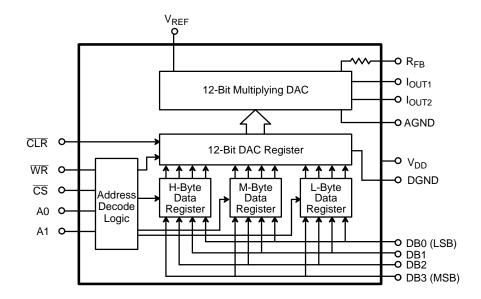
The MP7542 consists of three 4-bit registers, a 12-bit DAC register, address decoding logic, and a 12-bit CMOS multiplying DAC. Data is loaded into the data registers in three 4-bit nibbles and subsequently transferred to the 12-bit DAC register. All data loading or data transfer operations are identical to the WRITE

cycle of a static RAM. A CLEAR input allows the 12-bit DAC register to be reset to all zeros.

The MP7542 is manufactured using advanced thin-film on monolithic double metal CMOS fabrication process. A unique decoding technique is utilized yielding excellent accuracy and stability.

The MP7542 reduces the additional linearity errors due to output amplifier offset to only $330\mu V$ per millivolt of offset versus 670 μV for the standard R-2R ladder CMOS DACs.

SIMPLIFIED BLOCK DIAGRAM







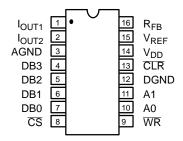
ORDERING INFORMATION

Package Type	Temperature Range	Part No.	INL (LSB)	DNL (LSB)	Gain Error (LSB)
Plastic Dip	–40 to +85°C	MP7542JN	<u>+</u> 1	<u>+</u> 2	<u>+</u> 14.5
Plastic Dip	–40 to +85°C	MP7542KN	<u>+</u> 1/2	<u>+</u> 1	<u>+</u> 14.5
SOIC	–40 to +85°C	MP7542JS	<u>+</u> 1	<u>+</u> 2	<u>+</u> 14.5
SOIC	–40 to +85°C	MP7542KS	<u>+</u> 1/2	<u>+</u> 1	<u>+</u> 14.5
Ceramic Dip	–40 to +85°C	MP7542AD	<u>+</u> 1	<u>+</u> 2	<u>+</u> 14.5
Ceramic Dip	–40 to +85°C	MP7542BD	<u>+</u> 1/2	<u>+</u> 1	<u>+</u> 14.5
Ceramic Dip	–55 to +125°C	MP7542SD*	<u>+</u> 1	<u>+</u> 2	<u>+</u> 14.5
Ceramic Dip	–55 to +125°C	MP7542TD*	<u>+</u> 1/2	<u>+</u> 1	<u>+</u> 14.5

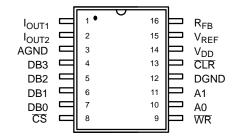
^{*}Contact factory for non-compliant military processing

PIN CONFIGURATIONS

See Packaging Section for Package Dimensions



16 Pin CDIP, PDIP (0.300") D16, N16



16 Pin SOIC (Jedec, 0.300") S16

PIN OUT DEFINITIONS

PIN NO.	NAME	DESCRIPTION			
1	I _{OUT1}	DAC current output. Normally terminated at op amp.			
2	I _{OUT2}	DAC current output. Normally terminated at ground.			
3	AGND	Analog Ground			
4	DB3	Data Input Bit 3 (MSB)			
5	DB2	Data Input Bit 2			
6	DB1	Data Input Bit 1			
7	DB0	Data Input Bit 0 (LSB)			

PIN NO.	NAME	DESCRIPTION			
8	CS	Chip Select Input			
9	WR	Write Input			
10	A0	Address Bus Input			
11	A1	Address Bus Input			
12	DGND	Digital Ground			
13	CLR	Clear Input			
14	V_{DD}	+5 V Supply Input			
15	V_{REF}	Reference Input			
16	R _{FB}	DAC Feedback Resistor			





ELECTRICAL CHARACTERISTICS

(V_{DD} = + 5 V, V_{REF} = +10 V unless otherwise noted)

Parameter	Symbol	Min	25°C Typ	Max	Tmin to Min	Tmax Max	Units	Test Conditions/Comments
STATIC PERFORMANCE ¹								
Resolution (All Grades)	N	12			12		Bits	
Integral Non-Linearity (Relative Accuracy) J, A, S K, B, T	INL			<u>+</u> 1 <u>+</u> 1/2		<u>+</u> 1 <u>+</u> 1/2	LSB	Best Fit Straight Line Spec. (Max INL – Min INL) / 2
Differential Non-Linearity J, A, S K, B, T	DNL			<u>+</u> 2 <u>+</u> 1		<u>+</u> 2 <u>+</u> 1	LSB	Monotonicity 11 Bits Guaranteed 12 Bits Guaranteed
Gain Error J, A, S, K, B, T	GE			<u>+</u> 12.3		<u>+</u> 14.5	LSB	Using Internal R _{FB}
Gain Temperature Coefficient ²	TC _{GE}					<u>+</u> 2	ppm/°C	∆Gain/∆Temperature
Power Supply Rejection Ratio	PSRR			<u>+</u> 50		<u>+</u> 100	ppm/%	$ \Delta Gain/\Delta V_{DD} \Delta V_{DD} = \pm 5\%$
Output Leakage Current	l _{OUT}			<u>+</u> 10		<u>+</u> 200	nA	
DYNAMIC PERFORMANCE								R _L =100Ω, C _L =13pF
Current Settling Time ² AC Feedthrough at I _{OUT1} ²	t _S F _T			2.0 2.5		2.0 2.5	μs mV p-p	Full Scale Change to 1/2 LSB V _{REF} = 10kHz, 20 Vp-p, sinewave
REFERENCE INPUT								
Input Resistance	R _{IN}	5	10	20	5	20	kΩ	
DIGITAL INPUTS ³ Logical "1" Voltage Logical "0" Voltage Input Leakage Current Input Capacitance ²	V _{IH} V _{IL} I _{LKG} C _{IN}	3.0		0.8 <u>+</u> 1 8	3.0	0.8 <u>+</u> 1 8	V V μΑ pF	
ANALOG OUTPUTS								
Output Capacitance ²	C _{OUT1} C _{OUT1} C _{OUT2} C _{OUT2}			260 100 50 210		260 100 50 210	pF pF pF pF	DAC Inputs all 1's DAC Inputs all 0's DAC Inputs all 1's DAC Inputs all 0's
POWER SUPPLY								
Supply Voltage ⁵ Supply Current	V _{DD} I _{DD}	+4.5		+5.5 2.5	+4.5	+5.5 2.5	V mA	All digital inputs = 0 V or all = 5 V



ELECTRICAL CHARACTERISTICS (CONT'D)

Parameter	Symbol	Min	25°C Typ	Max	Tmin to Min	Tmax Max	Units	Test Conditions/Comments
SWITCHING CHARACTERISTICS ^{2, 4}								
WR Pulse Width Address to WR Hold Time CS to WR Hold Time CLR Pulse Width Byte Loading, CS to WR Setup Byte Loading, Address to WR Setup Byte Loading, WR to Data Setup Byte Loading, WR to Data Hold DAC Loading, CS to WR Setup	twr tawh tcwh tclr tcws1 taws1 tbs tdh tcws2	120 50 50 200 60 80 50 50			220 65 100 300 130 180 65 65		ns	
DAC Loading, Address to WR Setup		120			240		ns	

NOTES:

- Full Scale Range (FSR) is 10V for unipolar mode.
- Guaranteed but not production tested.
- 3 Digital input levels should not go below ground or exceed the positive supply voltage, otherwise damage may occur.
- See timing diagram.
- Specified values guarantee functionality. Refer to other parameters for accuracy.

Specifications are subject to change without notice

ABSOLUTE MAXIMUM RATINGS (TA = +25°C unless otherwise noted)^{1, 2, 3}

V _{DD} to GND+7 V	Storage Temperature
Digital Input Voltage to GND (2) . GND -0.5 to V_{DD} +0.5 V	
I_{OUT1} , I_{OUT2} to GND GND -0.5 to V_{DD} +0.5 V	Lead Temperature (Soldering, 10 seconds) +300°C
V _{REF} to GND (2) <u>+</u> 25 V	Package Power Dissipation Rating to 75°C
V _{RFB} to GND (2) <u>+</u> 25 V	
AGND to DGND	CDIP, PDIP, SOIC
(Functionality Guaranteed ±0.5 V)	Derates above 75°C 10mW/°C

NOTES:

Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation at or above this specification is not implied. Exposure to maximum rating conditions for extended periods may affect device reliability.

Any input pin which can see a value outside the absolute maximum ratings should be protected by Schottky diode clamps (HP5082-2835) from input pin to the supplies. GND refers to AGND and DGND.

3





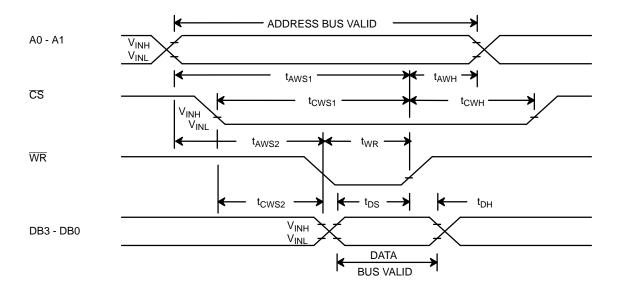


Figure 1. Timing Diagram

	MP7542 Control Inputs			ts	MD7542 Operation				
A 1	Αo	CS	WR	CLR	MP7542 Operation				
Х	Χ	Χ	Х	0	Resets DAC 12-bit register to code 0000 0000 0000				
Х	Х	1	1	1	No operation; device not selected				
0	0	_	0	1	Load LOW byte data register on edges as shown				
0	0	0	_	1	Load LOW byte data register on edges as shown	Load applicable			
0	1		0	1	Load MIDDLE byte data register on edges as shown Load MIDDLE byte data register on edges as shown D0 - D3				
0	1	0	_	1					
1	0		0	1					
1	0	0		1	Load HIGH byte data register on edges as shown				
1	1	0	0	1	Load 12-bit DAC register with data in LOW byte, MIDDLE				
1	1	0	0	1	byte, & HIGH byte data registers				

NOTES

- 1. 1 indicates logic HIGH
- 2. 0 indicates logic LOW
- 3. X indicates don't care
- 4. _/ indicates LOW to HIGH transition
- 5. MSB XXXX XXXX XXXX LSB high middle low byte byte byte
- 6. Although positive-going edge of either \overline{CS} or \overline{WR} will load data register, timing is optimized by using \overline{WR} to latch data and using \overline{CS} as a device enable.

Table 1. Truth Table





APPLICATION NOTES Refer to Section 8 for Applications Information

Interface Logic Information

The MP7542 is designed to interface as a memory-mapped output device.

A typical system configuration is shown below. \overline{CS} is the decoded device address, and is derived by decoding the 14 higher order address bits. A0 and A1 are the MP7542 operation address bits, and are decoded internally in the MP7542 to point to the desired loading operation (i.e. load high byte, middle byte, low byte or DAC register). See Table 1.

All data loading operations are identical to the write cycle of a RAM.

Additionally, the $\overline{\text{CLR}}$ input allows the MP7542 DAC register to be cleared asynchronously to 0000 0000 0000. When operat-

ing the MP7542 in a unipolar mode a CLEAR sets the DAC output to zero scale output. In the bipolar mode a CLEAR causes the DAC output to go to $-V_{REF}$.

In summary:

- 1. The MP7542 DAC register can be asynchronously cleared with the CLR input.
- 2. Each MP7542 requires only 4 bits of memory.
- Any of the four basic loading operations (i.e. load low byte data register, middle byte data register, high byte data register or 12-bit DAC register) are accomplished by executing a memory WRITE operation to the applicable address location for the required DAC operation.

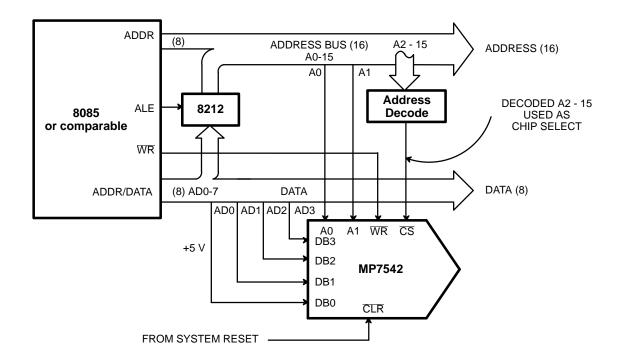
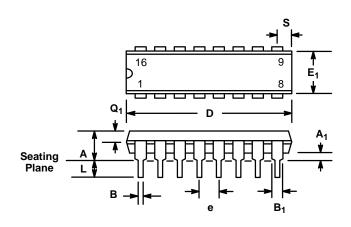
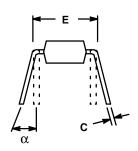


Figure 2. 8085/MP7542 Interface (Memory Mapped Output)



16 LEAD PLASTIC DUAL-IN-LINE (300 MIL PDIP) N16



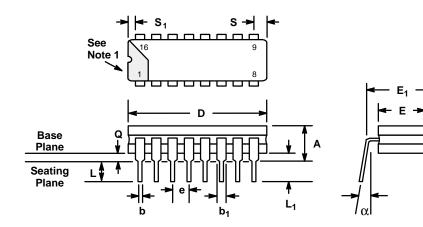


	INC	HES	MILLIN	METERS
SYMBOL	MIN	MAX	MIN	MAX
А		0.200		5.08
A ₁	0.015	_	0.38	_
В	0.014	0.023	0.356	0.584
B ₁ (1)	0.038	0.065	0.965	1.65
С	0.008	0.015	0.203	0.381
D	0.745	0.785	18.92	19.94
Е	0.295	0.325	7.49	8.26
E ₁	0.220	0.310	5.59	7.87
е	0.10	00 BSC	2.5	4 BSC
L	0.115	0.150	2.92	3.81
α	0°	15°	0°	15°
Q ₁	0.055	0.070	1.40	1.78
S	0.020	0.080	0.51	2.03

Note: (1) The minimum limit for dimensions B1 may be 0.023" (0.58 mm) for all four corner leads only.



16 LEAD CERAMIC DUAL-IN-LINE (300 MIL CDIP) D16



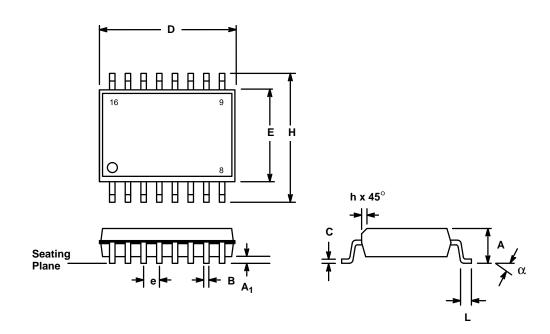
	INC	HES	MILLIN	METERS	
SYMBOL	MIN	MAX	MIN	MAX	NOTES
Α		0.200		5.08	
b	0.014	0.023	0.356	0.584	_
b ₁	0.038	0.065	0.965	1.65	2
С	0.008	0.015	0.203	0.381	_
D	_	0.840		21.34	4
E	0.220	0.310	5.59	7.87	4
E ₁	0.290	0.320	7.37	8.13	7
е	0.10	00 BSC	2.5	4 BSC	5
L	0.125	0.200	3.18	5.08	_
L ₁	0.150		3.81	_	_
Q	0.015	0.060	0.381	1.52	3
S	_	0.080		2.03	6
S ₁	0.005	_	0.13	_	6
α	0°	15°	0°	15°	_

NOTES

- Index area; a notch or a lead one identification mark is located adjacent to lead one and is within the shaded area shown.
- 2. The minimum limit for dimension b_1 may be 0.023 (0.58 mm) for all four corner leads only.
- 3. Dimension Q shall be measured from the seating plane to the base plane.
- 4. This dimension allows for off-center lid, meniscus and glass overrun.
- The basic lead spacing is 0.100 inch (2.54 mm) between centerlines.
- 6. Applies to all four corners.
- 7. This is measured to outside of lead, not center.



16 LEAD SMALL OUTLINE (300 MIL JEDEC SOIC) S16



	INC	CHES	MILLIN	METERS
SYMBOL	MIN	MAX	MIN	MAX
А	0.097	0.104	2.46	2.64
A ₁	0.0050	0.0115	0.127	0.292
В	0.014	0.019	0.356	0.482
С	0.0091	0.0125	0.231	0.318
D	0.402	0.412	10.21	10.46
Е	0.292	0.299	7.42	7.59
е	0.0	50 BSC	1.2	7 BSC
Н	0.400	0.410	10.16	10.41
h	0.010	0.016	0.254	0.406
L	0.016	0.035	0.406	0.889
α	0°	8°	0°	8°



Notes



Notes





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